

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|---------------------|
| L1 | 2 | ("5412246").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 12:28 |
| L2 | 0 | "5412246" and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:33 |
| L3 | 22 | "5412246" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:33 |
| L4 | 37 | sonos and low with temperature with plasma with oxid\$6 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:34 |
| L5 | 7038 | sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:40 |
| L6 | 1 | sonos same low with temperature with plasma with oxid\$6 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:40 |
| L7 | 8 | sonos same low with temperature with oxid\$6 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 12:41 |

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| L8 | 0 | sonos same embedded bitline | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:25 |
| L9 | 131 | embedded with bitline | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:25 |
| L10 | 2 | embedded with bitline and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:25 |
| L12 | 12 | embedded same bitline and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:26 |
| L13 | 2 | ("20040082198").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 13:29 |
| L14 | 5 | embedded same bit-line and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:29 |
| L15 | 1 | embedded and 13 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:30 |
| L16 | 0 | embedded bit-line-type and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:31 |

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| L17 | 0 | embedded same bit-line-type and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:31 |
| L18 | 2 | bit-line-type and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:31 |
| L19 | 0 | buried same bit-line-type and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:46 |
| L20 | 0 | buried same bit-line-type and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:46 |
| L21 | 0 | buried same bit-line and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:46 |
| L22 | 5 | embed\$4 same bit-line and sonos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 13:47 |
| L23 | 3599 | (438/257).CCLS. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 14:02 |
| L24 | 1185 | (438/770).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 14:03 |

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| L25 | 474 | (438/775).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 14:03 |
| L26 | 147 | (438/776).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 14:03 |
| L27 | 333 | NAKAMURA-MANABU.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:03 |
| L28 | 21 | UTSUNO-YUKIHIRO .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:03 |
| L30 | 18 | SERA-KENTARO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L31 | 42 | HIGASHI-MASAHIKO .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L32 | 42 | L31 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L33 | 21 | UTSUNO-YUKIHIRO .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |

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| L34 | 21 | L33 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L35 | 201 | TAKAGI-HIDEO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L36 | 201 | L35 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L37 | 69 | KAJITA-TATSUYA .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L38 | 69 | L37 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/11/23 14:04 |
| L39 | 1598 | (257/e21.228).CCLS. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/11/23 14:04 |
| S1 | 107 | nitric acid with "80" degrees | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S2 | 17 | nitric acid with "80" degrees and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |

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| S3 | 305 | heated with nitric acid and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S4 | 0 | heated with nitric acid with defect with removal and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 00:53 |
| S5 | 1 | heated with nitric acid with defect and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 00:55 |
| S6 | 305 | heated with nitric acid and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 00:55 |
| S7 | 31 | heated with nitric acid with oxide and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 00:57 |
| S8 | 13 | heated with nitric acid with known and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 01:00 |
| S9 | 22 | heat\$3 with nitric acid with known and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:02 |
| S10 | 0 | heat\$3 with nitric acid with known withoxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:03 |

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| S11 | 25 | heat\$3 with nitric acid with known with oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:03 |
| S12 | 0 | nitric acid with "80" degrees with known | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:07 |
| S13 | 34 | nitric acid with degrees with known | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:14 |
| S14 | 6 | nitric acid with degrees with known and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:15 |
| S15 | 0 | heated near nitric acid with known and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:16 |
| S16 | 33 | heated near nitric acid and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:35 |
| S17 | 198 | "hno.sub.3" and "80" degrees | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S18 | 13 | "hno.sub.3" with "80" degrees | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/03/30 10:36 |

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| S19 | 2 | ("6117689").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/03/31 14:28 |
| S20 | 5 | ("2005013689").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/03/31 14:29 |
| S21 | 2 | ("20050013689").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/03/31 14:30 |
| S22 | 1 | ("20050136689").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/03/31 14:30 |
| S23 | 206 | "hno.sub.3" and "80" degrees | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S24 | 107 | nitric acid with "80" degrees | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S25 | 17 | nitric acid with "80" degrees and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:12 |
| S26 | 310 | heated with nitric acid and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:24 |

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|-----|------|--|---|-----|-----|---------------------|
| S27 | 3923 | (438/694).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:24 |
| S28 | 414 | (438/695).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S29 | 1314 | (438/745).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S30 | 371 | (438/775).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S31 | 120 | (438/776).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S32 | 1033 | (438/770).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S33 | 34 | nitric acid with degrees with known | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:14 |
| S34 | 278 | NAKAMURA-MANABU.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:25 |

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| S35 | 13 | NANSEI-HIROYUKI.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S36 | 12 | SERA-KENTARO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S37 | 25 | HIGASHI-MASAHIKO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S38 | 10 | UTSUNO-YUKIHIRO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2006/06/25 15:16 |
| S39 | 185 | TAKAGI-HIDEO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S40 | 63 | KAJITA-TATSUYA.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S41 | 74 | (257/e21.221).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/25 15:21 |
| S42 | 4 | tunnel oxide with plasma oxidation | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:27 |

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|-----|-----|---|---|-----|----|---------------------|
| S43 | 3 | nitric acid and tunnel oxide and plasma with oxidation | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:29 |
| S44 | 335 | nitric acid with clean\$3 same semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:30 |
| S45 | 1 | nitric acid with clean\$3 same semiconductor and tunnel oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:31 |
| S46 | 108 | nitric acid with clean\$3 same semiconductor same oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:33 |
| S47 | 7 | nitric acid with clean\$3 same semiconductor same oxide and plasma with oxid\$6 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:27 |
| S48 | 16 | "5423944" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/07 12:42 |
| S49 | 518 | acid with ozone and plasma with oxidation | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/26 13:14 |
| S50 | 18 | acid with ozone and plasma with oxidation and insulation film | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/26 18:24 |

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| S51 | 2 | ("5423944").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/02/26 18:29 |
| S52 | 117 | nitric acid with ozone same silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/26 18:30 |
| S53 | 25 | nitric acid with ozone same silicon same temperature | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/02/26 18:31 |
| S54 | 2 | ("5412216").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/02/26 20:05 |
| S55 | 2 | ("5412246").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/02/26 20:05 |
| S56 | 2 | ("5423944").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 06:55 |
| S57 | 2 | ("5412246").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 06:54 |
| S58 | 4054 | (438/694).OCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:24 |

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| S59 | 347 | heated with nitric acid and semiconductor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:25 |
| S60 | 455 | (438/695).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S61 | 1535 | (438/745).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S62 | 428 | (438/775).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S63 | 138 | (438/776).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S64 | 1118 | (438/770).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:25 |
| S65 | 308 | NAKAMURA-MANABU.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:25 |
| S66 | 20 | NANSEI-HIROYUKI.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |

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| S67 | 14 | SERA-KENTARO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S68 | 38 | HIGASHI-MASAHIKO .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S69 | 192 | TAKAGI-HIDEO.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S70 | 65 | KAJITA-TATSUYA .in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:26 |
| S71 | 8 | nitric acid with clean\$3 same semiconductor same oxide and plasma with oxid\$6 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2007/08/06 07:39 |
| S72 | 1569 | (257/e21.228).CCLS. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/08/06 07:39 |
| S73 | 193 | radial line slot antenna with plasma with microwave | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/02/27 21:18 |
| S74 | 7 | radial line slot antenna with plasma with microwave same insulation film | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/02/27 21:18 |

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| S76 | 68 | (radial line slot antenna or rlsa) with plasma same microwave and insulation film | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/02/27 21:25 |
| S77 | 7 | (radial line slot antenna or rlsa) with plasma same microwave same insulation film | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/05/01 17:19 |

11/23/2008 2:05:18 PM

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